



Standard Rectifier Module

 $V_{RRM} = 2x 1600 V$

 $I_{\text{FAV}} = 700 \,\text{A}$

 $V_F = 1.05 V$

Phase leg

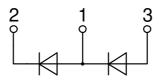
Part number

MDMA700P1600CC



Backside: isolated





Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: ComPack

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Base plate: Copper internally DCB isolated
- Advanced power cycling
- Phase Change Material available

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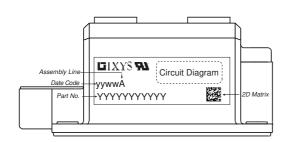


Rectifier				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse bloc	king voltage	$T_{VJ} = 25^{\circ}C$			1700	V
V _{RRM}	max. repetitive reverse blocking	voltage	$T_{VJ} = 25^{\circ}C$			1600	V
I _R	reverse current	V _R = 1600 V	$T_{VJ} = 25^{\circ}C$			500	μΑ
		$V_R = 1600 \text{ V}$	$T_{VJ} = 150$ °C			20	mΑ
V _F	forward voltage drop	I _F = 700 A	$T_{VJ} = 25^{\circ}C$			1.14	V
		$I_F = 1400 \text{ A}$				1.35	٧
		$I_F = 700 \text{ A}$	T _{VJ} = 125°C			1.05	V
		$I_F = 1400 \text{ A}$				1.30	٧
IFAV	average forward current	T _C = 100°C	T _{vJ} = 150°C			700	Α
		rectangular d = 0.5					1 1 1 1
V _{F0}	threshold voltage $T_{vJ} = 150$ °C					0.78	V
r _F	slope resistance } for power	loss calculation only				0.35	mΩ
R _{thJC}	thermal resistance junction to ca	ase				0.055	K/W
R _{thCH}	thermal resistance case to heats	sink			0.02		K/W
P _{tot}	total power dissipation		$T_{C} = 25^{\circ}C$			2270	W
I _{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			20.0	kA
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			21.6	kA
		t = 10 ms; (50 Hz), sine	T _{vJ} = 150°C			17.0	kA
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			18.4	kA
I²t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			2.00	MA ² s
		t = 8,3 ms; (60 Hz), sine	$V_R = 0 V$			1.94	MA ² s
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150$ °C			1.45	MA ² s
		t = 8.3 ms; (60 Hz), sine	$V_R = 0 V$			1.40	MA ² s
CJ	junction capacitance	$V_R = 400 \text{ V}; f = 1 \text{ MHz}$	$T_{VJ} = 25^{\circ}C$		781		pF



MDMA700P1600CC

Package ComPack				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
I _{RMS}	RMS current	per terminal				1200	Α
T _{VJ}	virtual junction temperature			-40		150	°C
T _{op}	operation temperature			-40		125	°C
T _{stg}	storage temperature			-40		125	°C
Weight					500		g
M _D	mounting torque			3		5	Nm
\mathbf{M}_{T}	terminal torque			12		14	Nm
d _{Spp/App}	creepage distance on surface striking distance throug		terminal to terminal	21.0			mm
$d_{Spb/Apb}$			terminal to backside	18.0			mm
V _{ISOL}	isolation voltage	t = 1 second	50/60 Hz, RMS; IIsoL ≤ 1 mA	4800			V
		t = 1 minute		4000			٧



Part description

M = Module

D = Diode
M = Standard Rectifier

A = (up to 1800V) 700 = Current Rating [A]

P = Phase leg 1600 = Reverse Voltage [V]

CC = ComPack

Orderin	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standar	MDMA700P1600CC	MDMA700P1600CC	Box	3	514708

Equivalent Circuits for Simulation		* on die level	$T_{VJ} = 150$ °C	
$I \rightarrow V_0$)— <u>R</u> o	Rectifier		
V _{0 max}	threshold voltage	0.78		V
R_{0max}	slope resistance *	0.16		mΩ





Outlines ComPack

